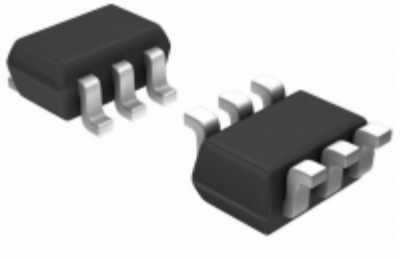

	<p>Hersteller-Teilenummer: SI1410EDH-T1-E3</p>
	<p>Hersteller / Marke: Vishay / Siliconix</p>
	<p>Teil der Beschreibung: MOSFET N-CH 20V 2.9A SC70-6</p>
	<p>Datenblätter:  SI1410EDH-T1-E3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 1200 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SI1410EDH-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 2.9A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1200 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	1W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.9A (Ta)
Rds On (Max) @ Id, Vgs	70 mOhm @ 3.7A, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	8nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



































SI1410EDH-T1-E3 ist neu im Original. Suche SI1410EDH-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1410EDH-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1410EDH-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1410EDH VISHAY SI1410EDH VISHAY</p>	 <p>SI1407DL-T1-GE3 V SI1407DL-T1-GE3 V</p>	 <p>SI1407DL-T1-E3 VISHAY SI1407DL-T1-E3 VISHAY</p>	 <p>SI1411DH-T1-GE3 Vishay / Siliconix MOSFET P-CH 150V 420MA SC70</p>
 <p>SI1411DH-T1-E3 Vishay / Siliconix MOSFET P-CH 150V 0.42A SC70-6</p>	 <p>SI1411DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 150V 0.42A SC70-6</p>	 <p>SI1411DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 150V 420MA SC70</p>	 <p>SI1410EDH-T1-GE3 VISHAY SI1410EDH-T1-GE3 VISHAY</p>

heiße Teile

Mehr

- | | | | | |
|--|--|--|--|---|
|  SI1404BDH-T1-E3 |  SI1404DH-T1 |  SI1404DH-T1-E3 |  SI1404DH-T1-GE3 |  SI1404DL-T1-GE3 |
|  SI1405BDH-T1-E3 |  SI1405BDH-T1-E3 |  SI1405BDH-T1-GE3 |  SI1405BDH-T1-GE3 |  SI1405DL-T1 |
|  SI1405DL-T1-E3 |  SI1405DL-T1-E3 |  SI1406DH |  SI1406DH-T1 |  SI1406DH-T1-E3 |
|  SI1406DH-T1-E3 |  SI1406DH-T1-GE3 |  SI1406DH-T1-GE3 |  SI1407DL |  SI1407DL-T1 |
|  SI1407DL-T1-E3 |  SI1407DL-T1-GE3 |  SI1410EDH |  SI1410EDH-T1 |  SI1410EDH-T1-E3 |
|  SI1410EDH-T1-GE3 |  SI1413DH-T1 |  SI1413EDH |  SI1413EDH-T1 |  SI1413EDH-T1-E3 |
|  SI1413EDH-T1-E3 |  SI1413EDH-T1-GE3 |  SI1413EDH-T1-GE3 |  SI1414DH-T1-GE3 |  SI1414DH-T1-GE3 |
|  SI1416EDH-T1-GE3 |  SI1416EDH-T1-GE3 |  SI1417DH-T1-E3 |  SI1417DH-T1-GE3 |  SI1417EDH-T1 |
|  SI1417EDH-T1-E3 |  SI1417EDH-T1-E3 |  SI1417EDH-T1-GE3 |  SI1417EDH-T1-GE3 |  SI1422DH-T1-GE3 |
|  SI1422DH-T1-GE3 |  SI1424EDH-T1-GE3 |  SI1424EDH-T1-GE3 |  SI1426DH-T1-E3 |  SI1426DH-T1-E3 |

Contact us: Info@Y-IC.com

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